



**THE DATASHEET OF
AS6214-AWLT-S**



Product Overview

Qorvo's QPA1019 is a packaged high-power, C-band amplifier fabricated on Qorvo's production 0.15 um GaN on SiC process (QGaN15). Covering 4.5–7.0 GHz, the QPA1019 provides greater than 10 W of saturated output power and 19 dB of large-signal gain while achieving greater than 39% power-added efficiency.

The QPA1019 is packaged in a plastic overmold QFN with a Cu paddle offering easy handling with good thermal properties. As a result, the QPA1019 has bias flexibility allowing the user to vary the voltage to achieve optimum system performance while maintaining high reliability.

The QPA1019 is matched to 50 ohms with integrated DC blocking caps on both I/O ports. With the high performance, good thermal characteristics and ease of handling and system integration, the QPA1019 is ideal for radar and satellite communication systems.

Lead-free and RoHS compliant.

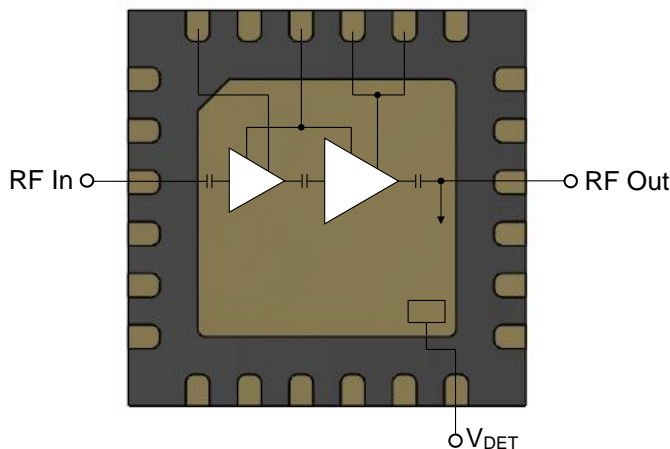


Key Features

- Frequency Range: 4.5–7.0 GHz
- P_{SAT} ($P_{IN}=22$ dBm): > 40 dBm
- PAE ($P_{IN}=22$ dBm): > 40 %
- Power Gain ($P_{IN}=22$ dBm): > 19 dB
- Integrated Power Detector
- Bias: $V_D = 22$ V, $I_{DQ} = 290$ mA, $V_G = -2.5$ V typical
- Package Dimensions: 5.0 x 5.0 x 0.85 mm

Performance is typical across frequency. Please reference electrical specification table and data plots for more details.

Functional Block Diagram



Applications

- C-Band Radar
- Satellite Communication

Ordering Information

| Part No. | Description |
|------------|--------------------------------------|
| QPA1019 | 4.5 – 7.0GHz 10W GaN Power Amplifier |
| QPA1019S2 | Samples (2 pcs. pack) |
| QPA1019TR7 | 250 pieces on a 7" reel (standard) |
| QPA1019EVB | Evaluation Board for QPA1019 |

Absolute Maximum Ratings

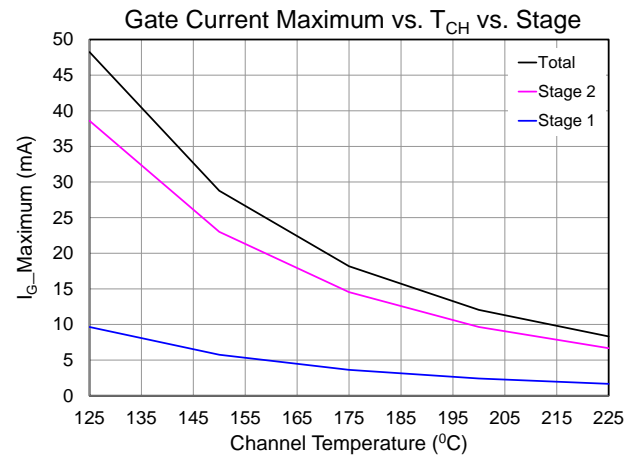
| Parameter | Value / Range |
|--|---------------|
| Drain Voltage (V_D) | 29.5 |
| Gate Voltage Range (V_G) | -6 to 0 V |
| Drain Current (I_{D1} , I_{D2}) | 0.52, 2.0 A |
| Gate Current (I_G) | See chart |
| Power Dissipation (P_{DISS}), CW, 85°C | 25.2 W |
| Input Power (P_{IN}), CW, 50 Ω , $V_D=22$ V, $I_{DQ}=290$ mA, 85 °C | 28 dBm |
| Input Power (P_{IN}), CW, 4:1 VSWR, $V_D=22$ V, $I_{DQ}=290$ mA, 85 °C | 25 dBm |
| Channel Temperature (T_{CH}) | 275 °C |
| Mounting Temperature (30 seconds) | 260 °C |
| Storage Temperature | -55 to 150 °C |

Operation of this device outside the parameter ranges given above may cause permanent damage. These are stress ratings only, and functional operation of the device at these conditions is not implied.

Recommended Operating Conditions

| Parameter | Min | Typ | Max | Units |
|---------------------------------------|-----------------------|-----|-----|-------|
| Drain Voltage (V_D) | | +22 | | V |
| Drain Current, Quiescent (I_{DQ}) | | 290 | | mA |
| Drain Current, RF (I_{D_Drive}) | See charts page 3 - 8 | | | mA |
| Gate Voltage Typ. Range (V_G) | -2 to -2.8 | | | V |
| Gate Current, RF (I_{G_Drive}) | See charts page 5 - 8 | | | mA |
| Operating Temp. Range | -40 | +25 | +85 | °C |

Electrical specifications are measured at specified test conditions. Specifications are not guaranteed over all recommended operating conditions.



Electrical Specifications

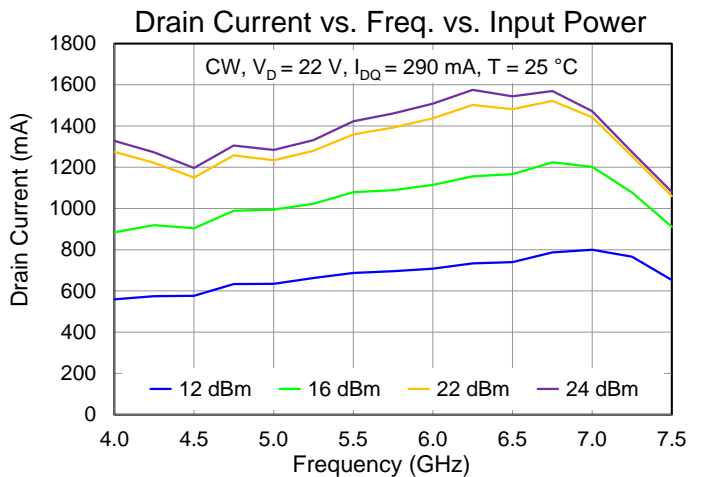
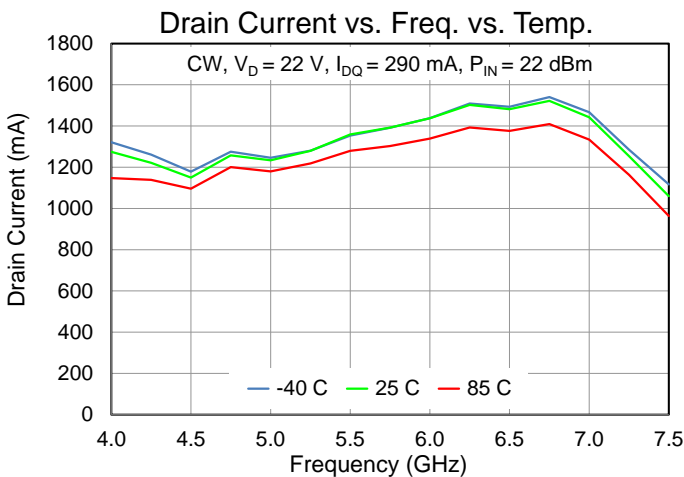
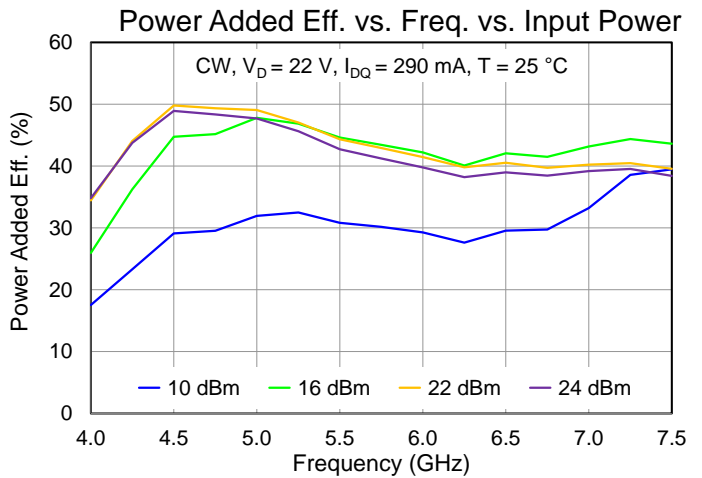
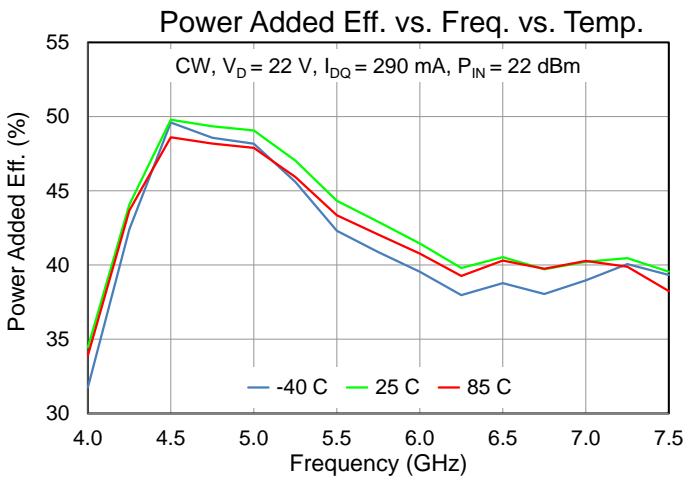
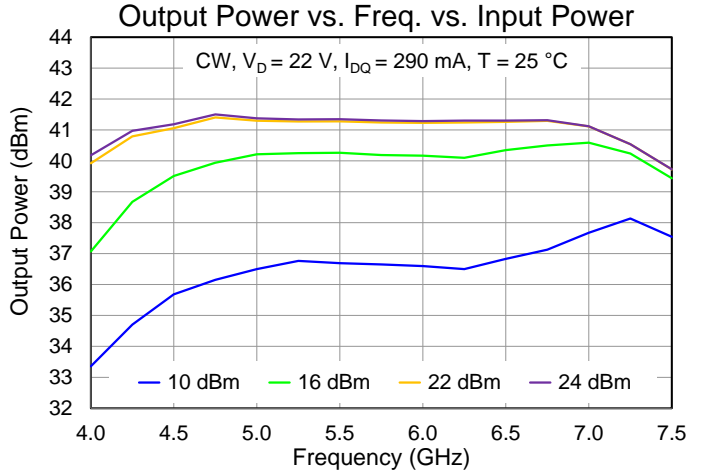
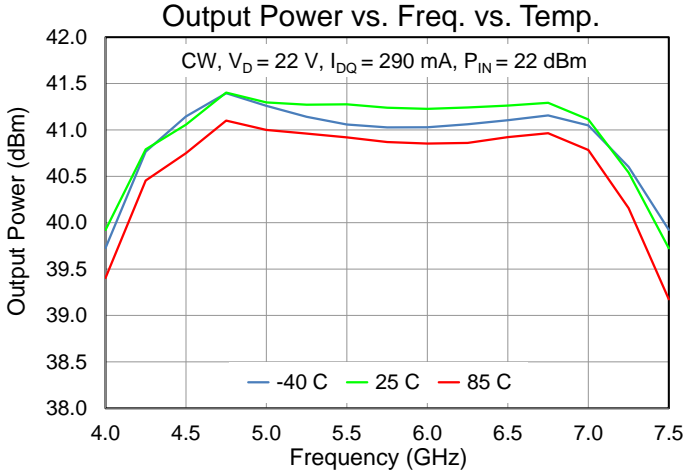
| Parameter | Conditions ^{(1) (2)} | Min | Typ | Max | Units |
|---|--|-----|--------|-----|--------|
| Operational Frequency Range | | 4.5 | | 7.0 | GHz |
| Output Power at Saturation, P_{SAT} | $P_{IN} = +22$ dBm | 39 | 41 | | dBm |
| Power Added Efficiency, PAE | $P_{IN} = +22$ dBm; Frequency = 4.5 – 5.5 GHz | 35 | 45 | | % |
| | $P_{IN} = +22$ dBm; Frequency = 6.0 – 7.0 GHz | | 40 | | |
| Small Signal Gain, S_{21} | | | 30 | | dB |
| Input Return Loss, IRL | | | 15 | | dB |
| Output Return Loss, ORL | | | 7 | | dB |
| 3 RD Intermodulation Products, IM3 | $P_{OUT/TONE} = +32$ dBm; Frequency = 5.7 GHz | | -25 | | dBc |
| P_{SAT} Temperature Coefficient | $T_{DIFF} = +25^\circ\text{C}$ to $+85^\circ\text{C}$; $P_{IN} = +22$ dBm | | -0.007 | | dBm/°C |
| S_{21} Temperature Coefficient | $T_{DIFF} = -40^\circ\text{C}$ to $+85^\circ\text{C}$ | | -0.050 | | dB/°C |

Notes:

- Test conditions unless otherwise noted: CW, $V_D = 22$ V, $I_{DQ} = 290$ mA, $V_G = -2.5$ V +/- typical, $T_{BASE} = +25$ °C, $Z_0 = 50$ Ω
- T_{BASE} is back side of package

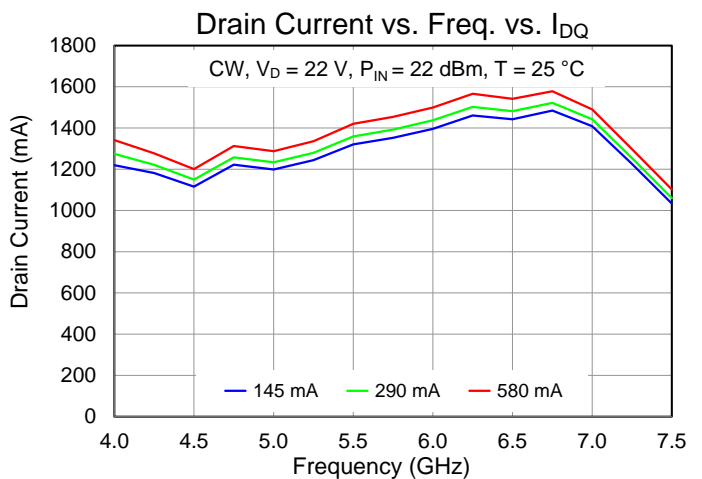
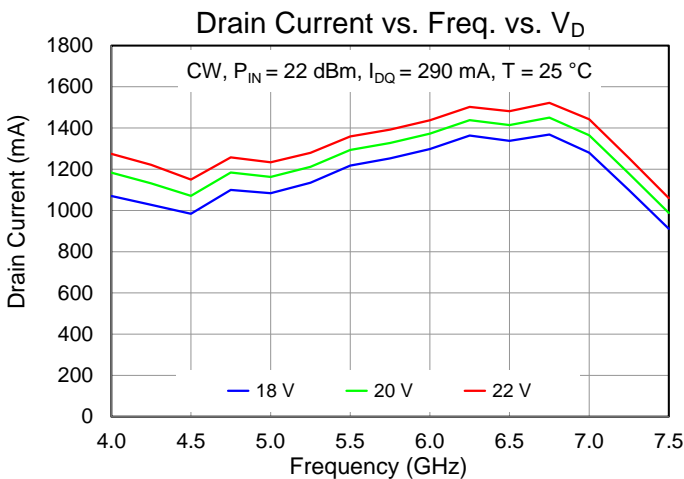
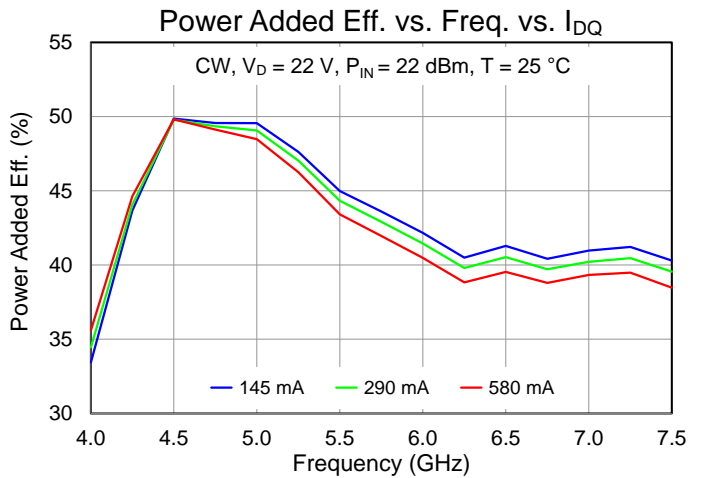
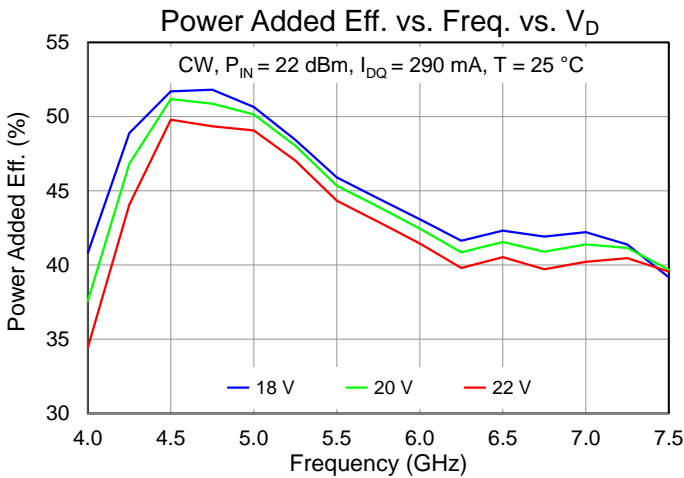
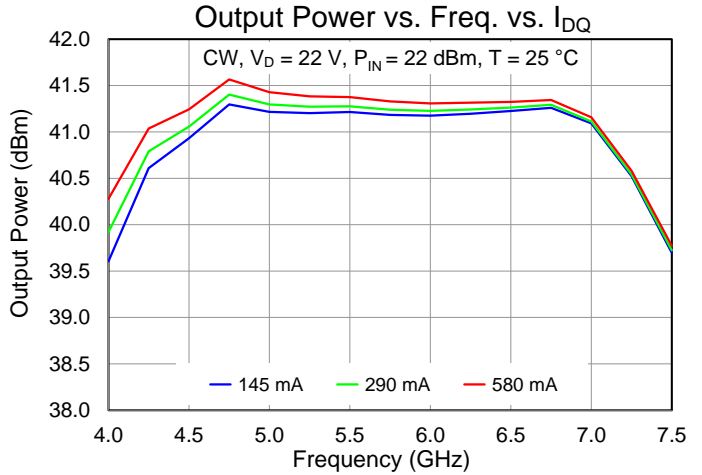
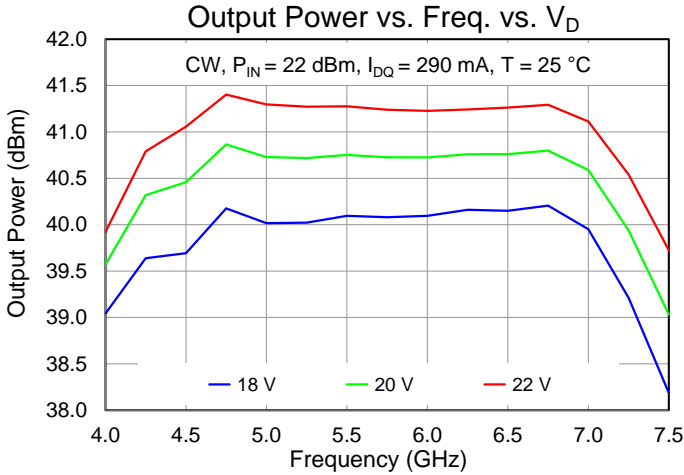
Performance Plots – Large Signal

Test conditions unless otherwise noted: CW $V_D = 22\text{ V}$, $I_{DQ} = 290\text{ mA}$, CW input power, $T = +25\text{ }^\circ\text{C}$



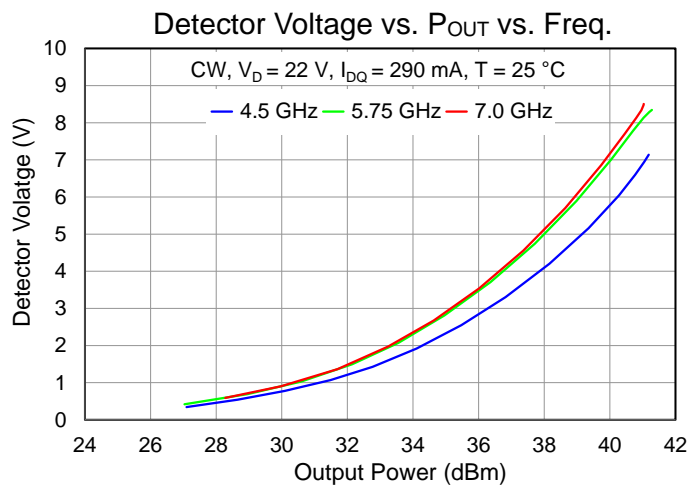
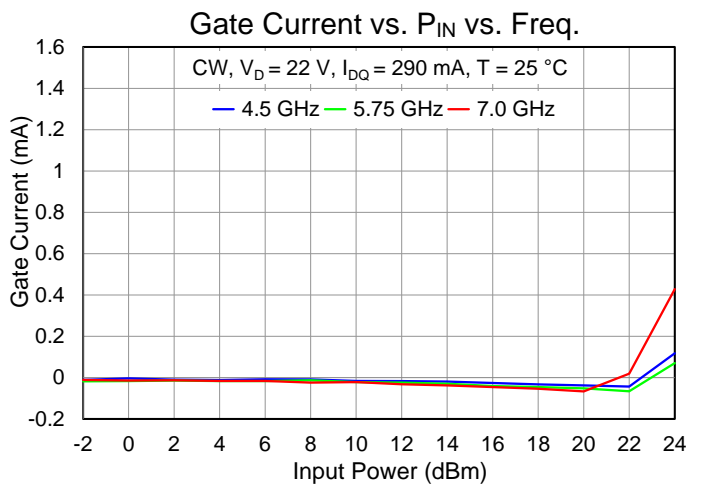
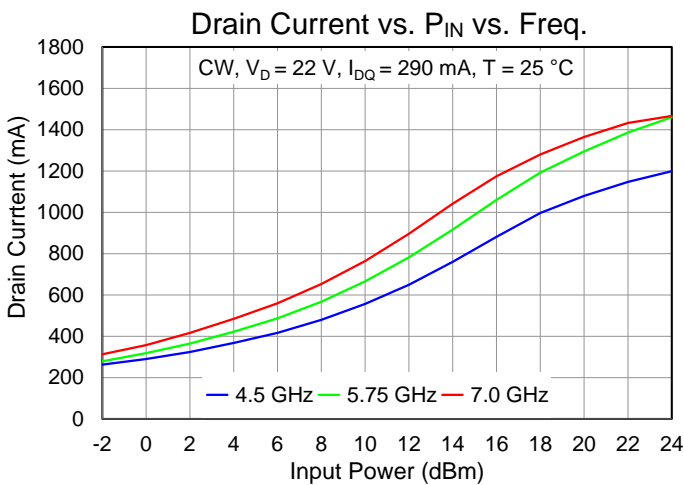
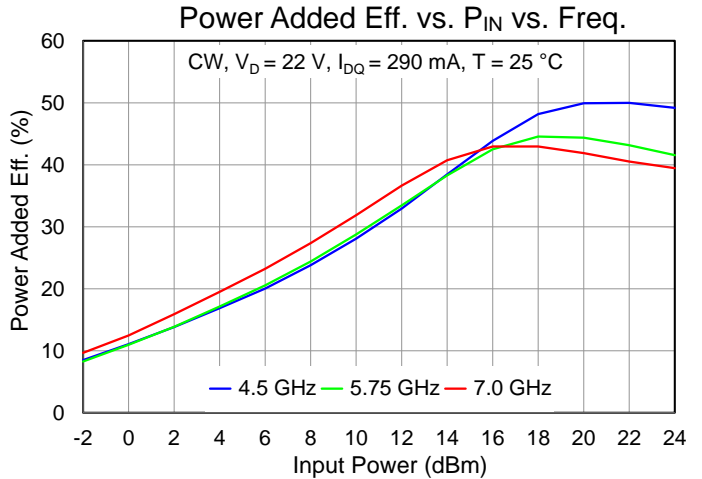
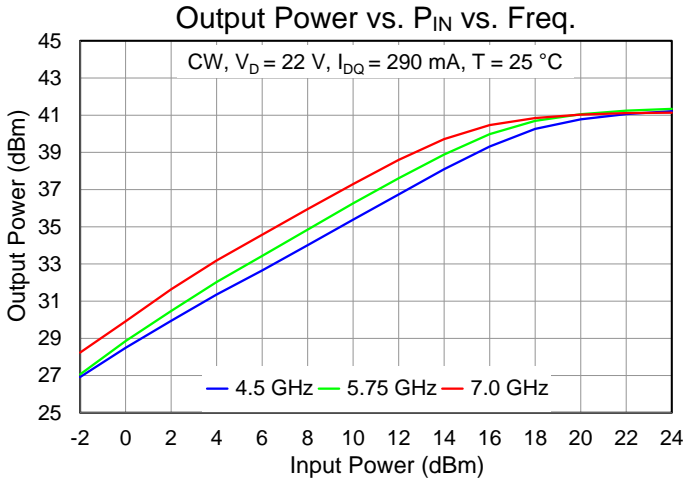
Performance Plots – Large Signal

Test conditions unless otherwise noted: **CW** $V_D = 22\text{ V}$, $I_{DQ} = 290\text{ mA}$, CW input power, $T = +25\text{ }^\circ\text{C}$



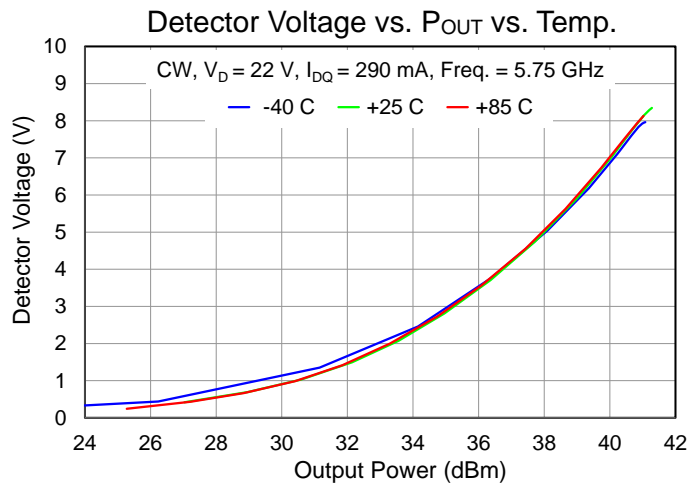
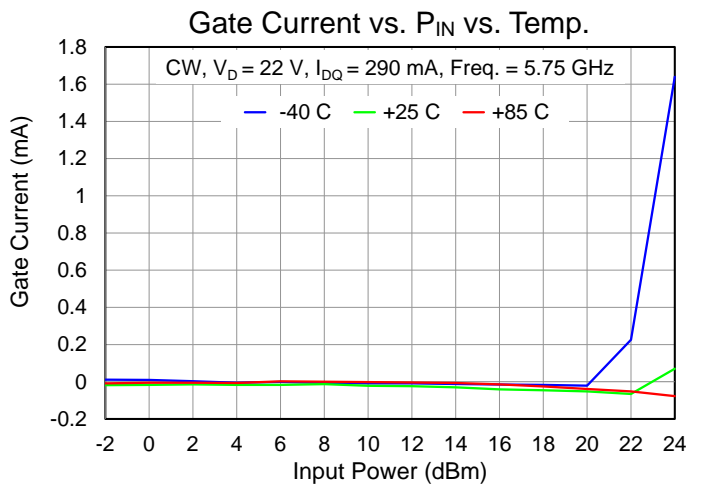
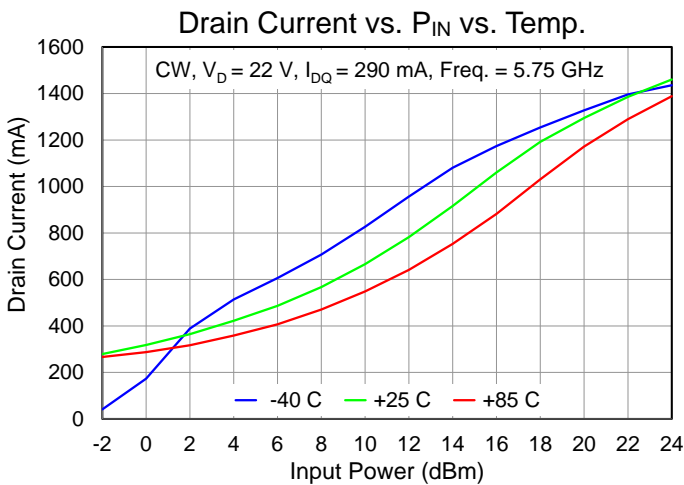
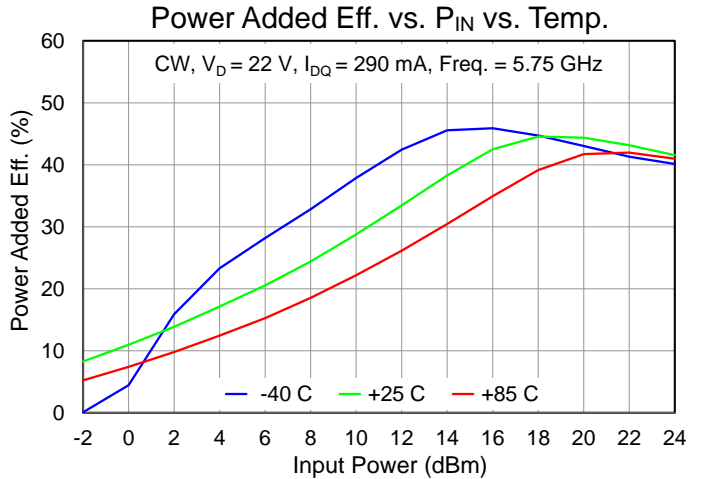
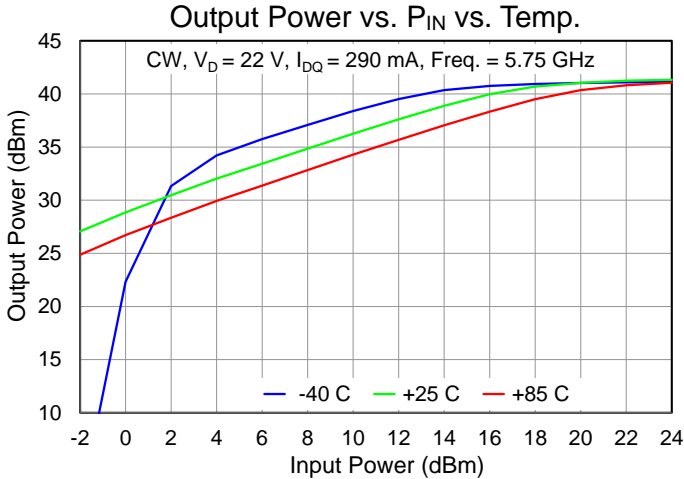
Performance Plots – Large Signal

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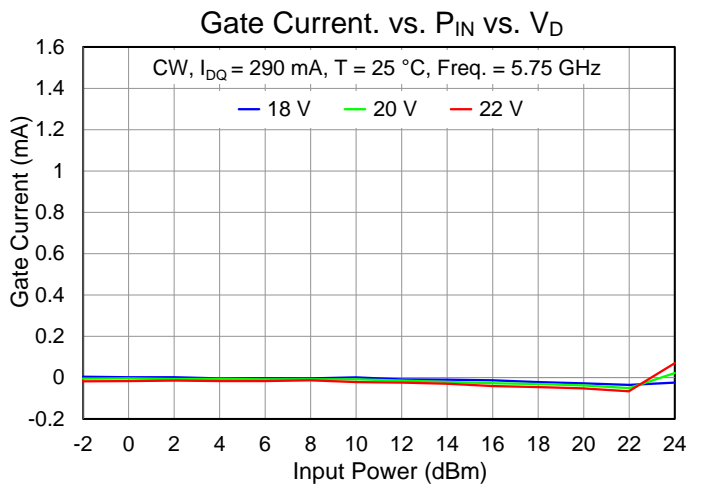
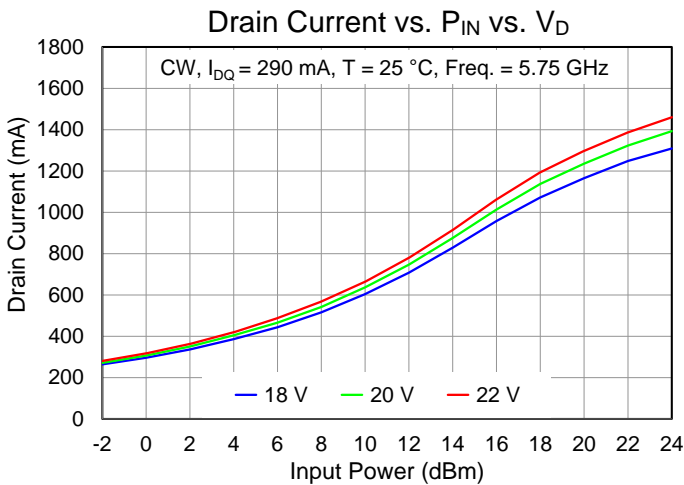
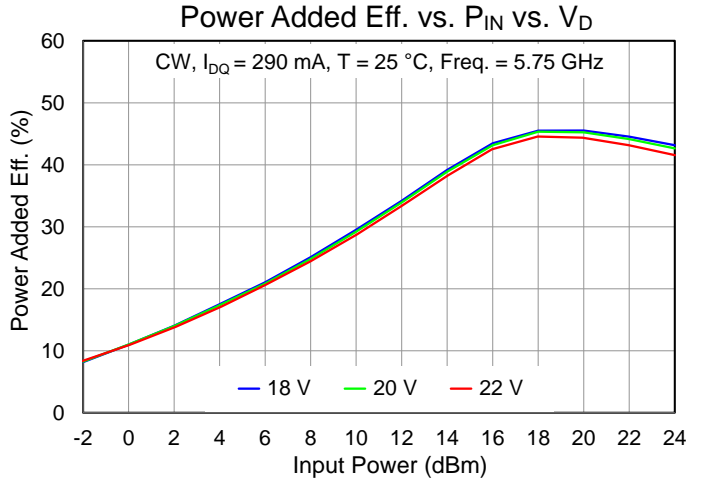
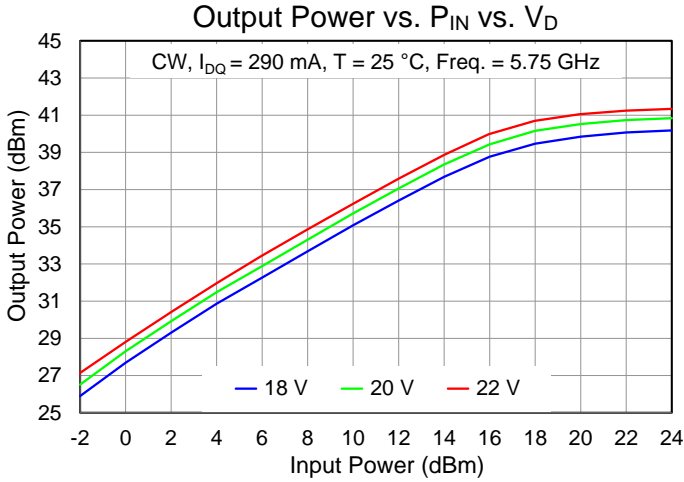
Performance Plots – Large Signal

Test conditions unless otherwise noted: CW, $V_D = 22$ V, $I_{DQ} = 290$ mA, CW input power, $T = +25$ °C



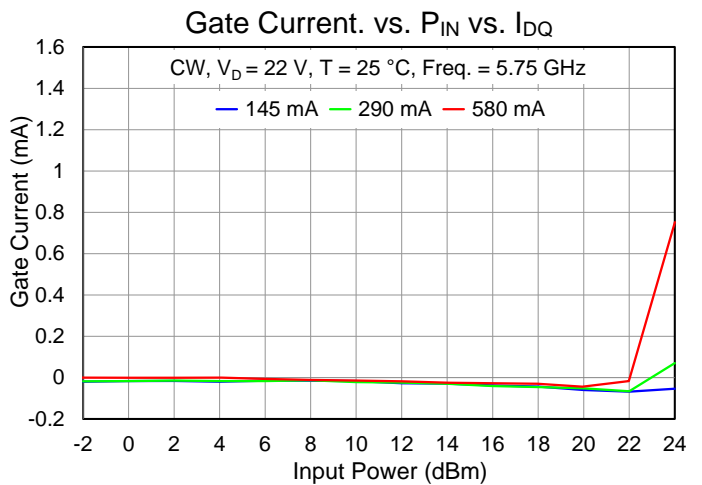
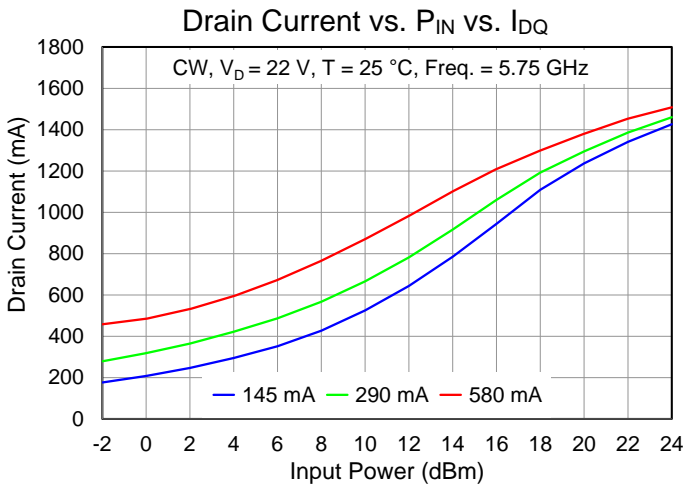
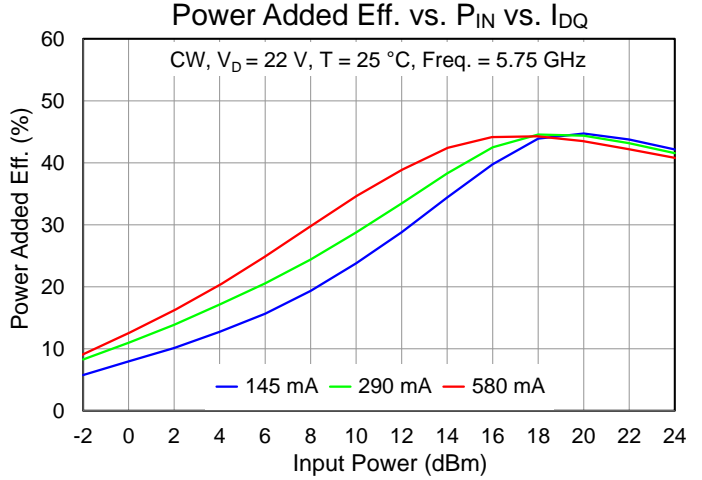
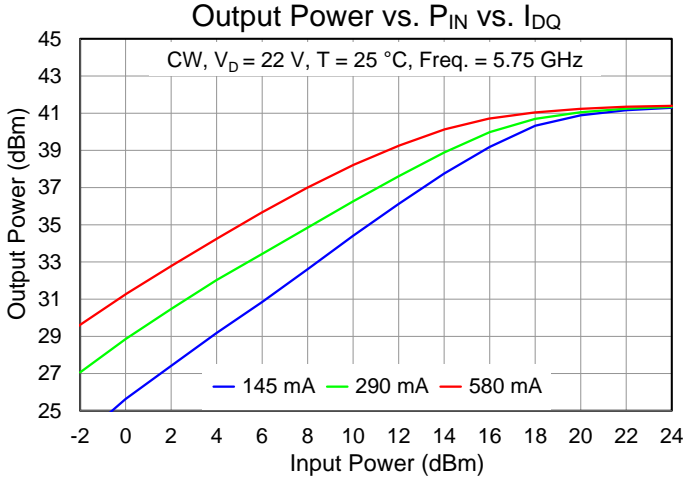
Performance Plots – Large Signal

Test conditions unless otherwise noted: CW $V_D = 22\text{ V}$, $I_{DQ} = 290\text{ mA}$, CW input power, $T = +25\text{ }^\circ\text{C}$



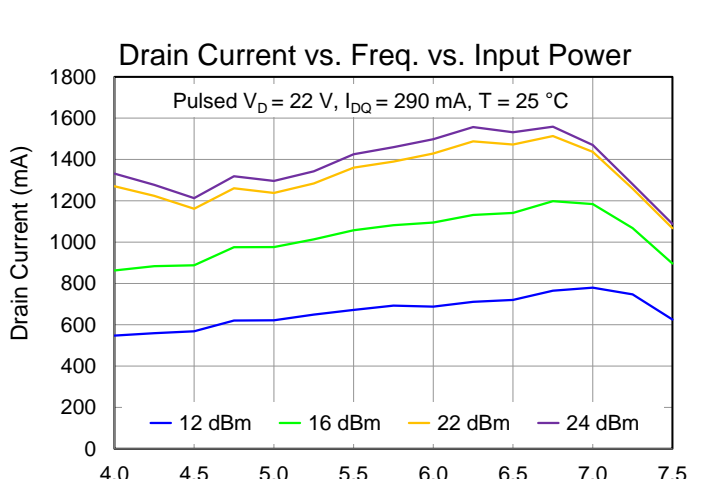
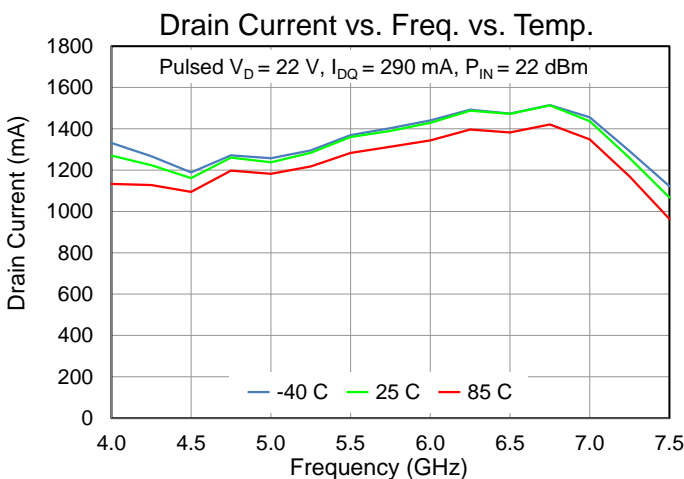
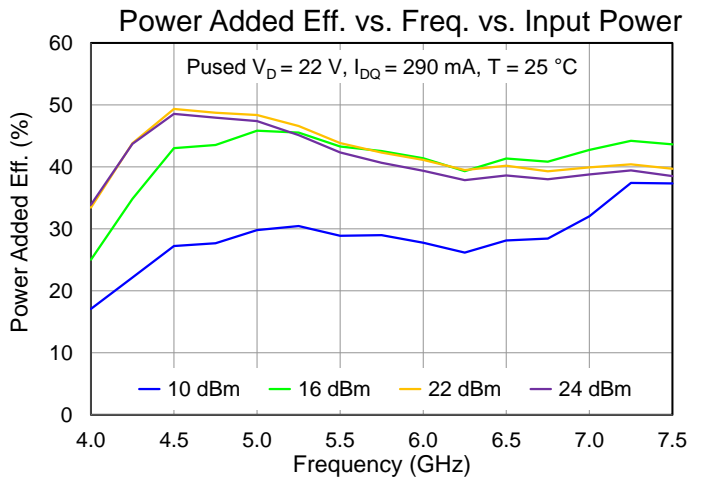
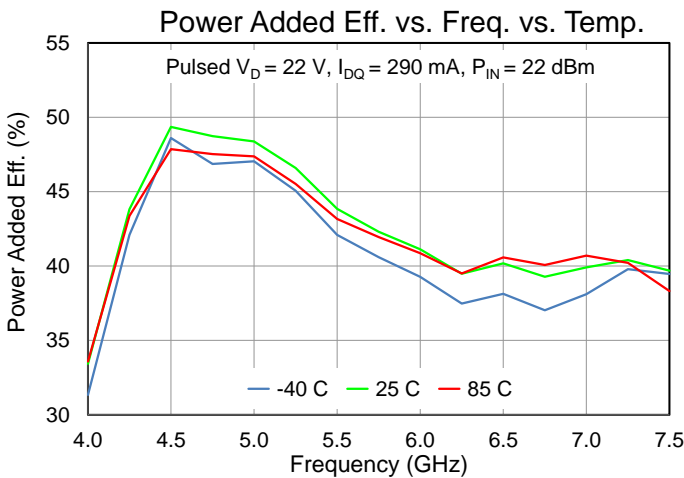
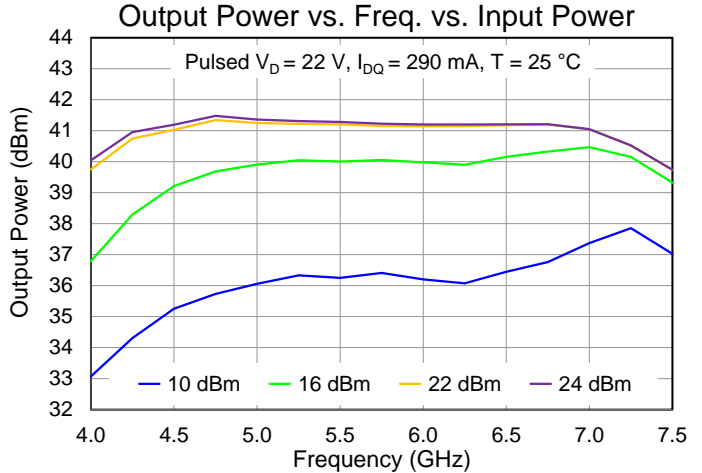
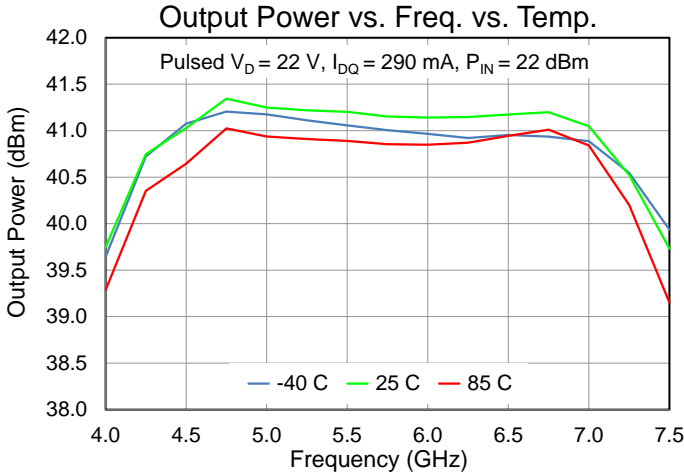
Performance Plots – Large Signal

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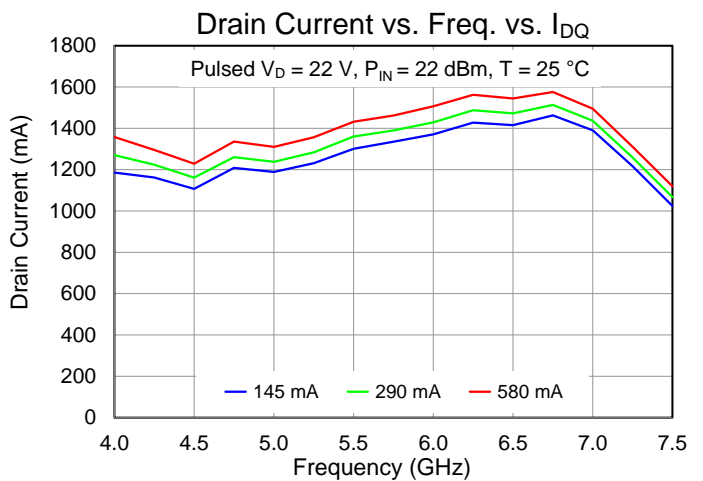
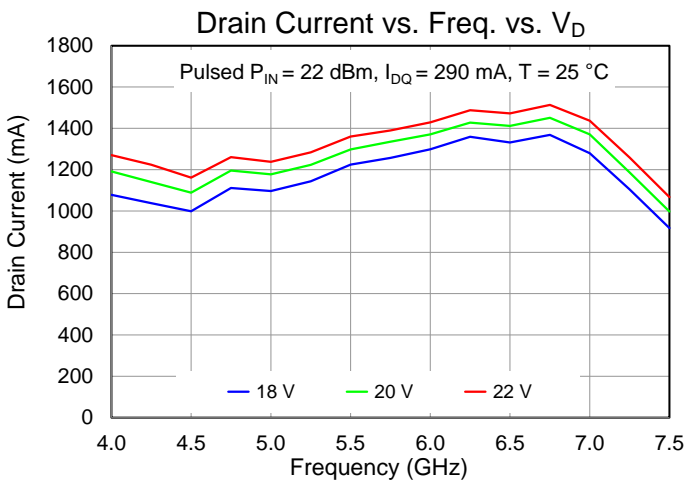
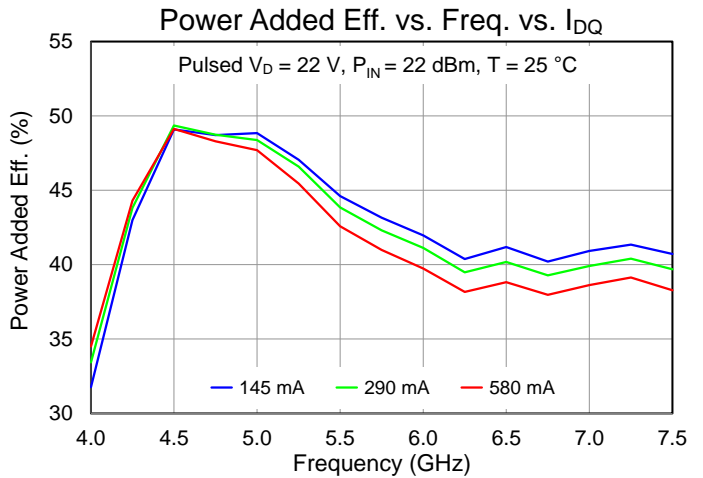
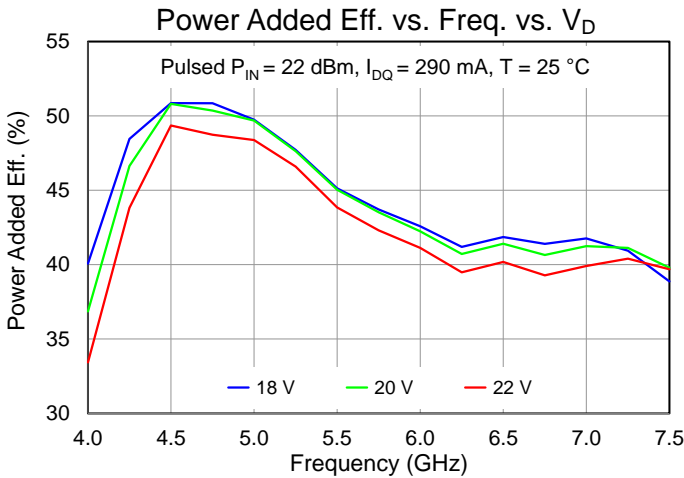
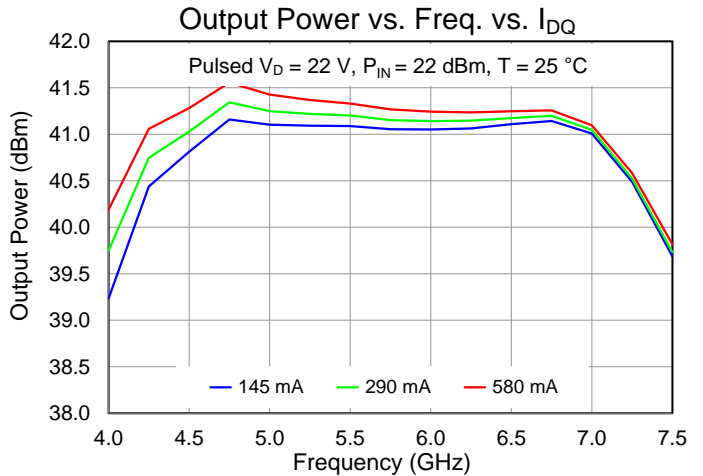
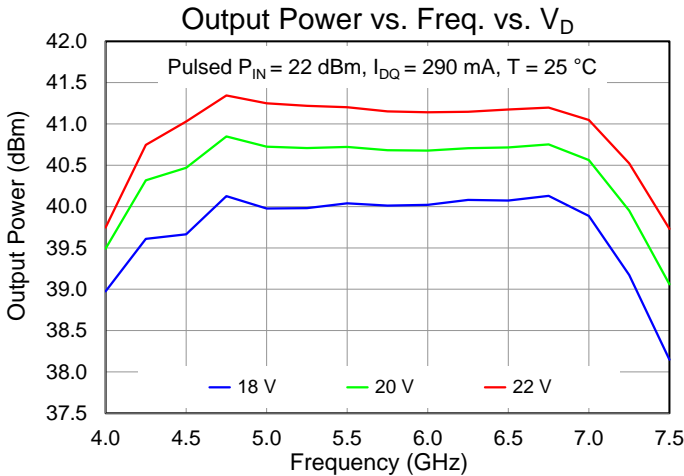
Performance Plots – Large Signal

Test conditions unless otherwise noted: Pulsed $V_D = 22\text{ V}$, $I_{DQ} = 290\text{ mA}$, Duty Cycle = 10%, PW = 100 us, CW input power, $T = +25\text{ }^\circ\text{C}$



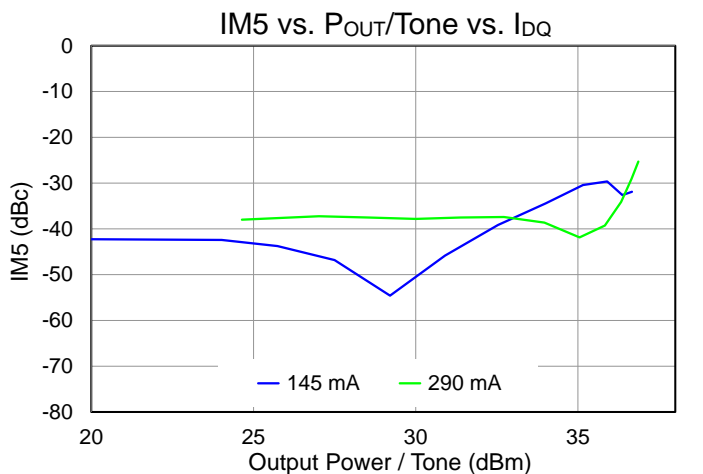
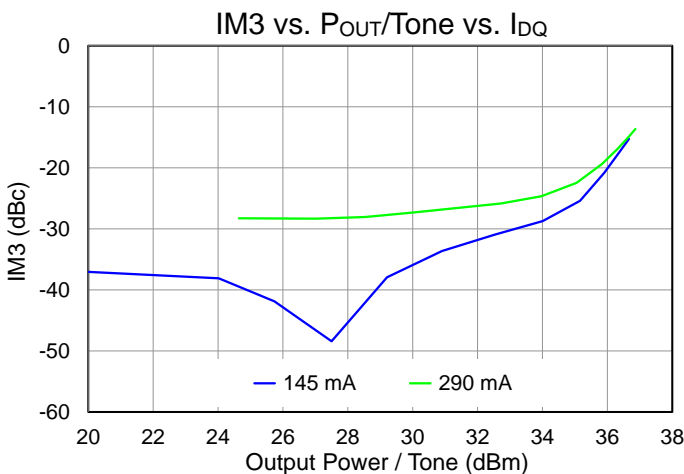
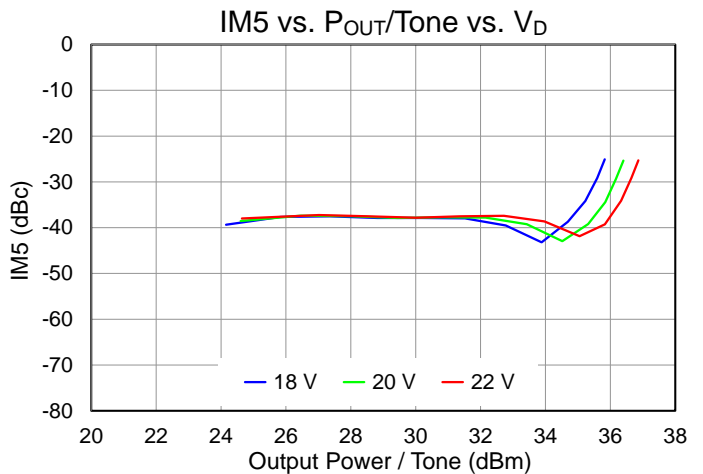
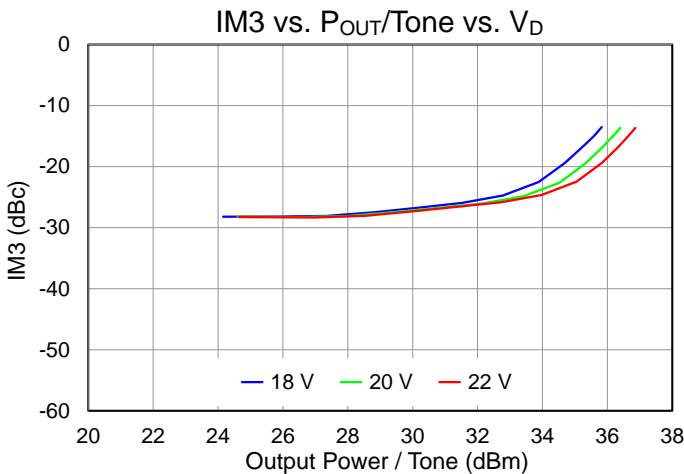
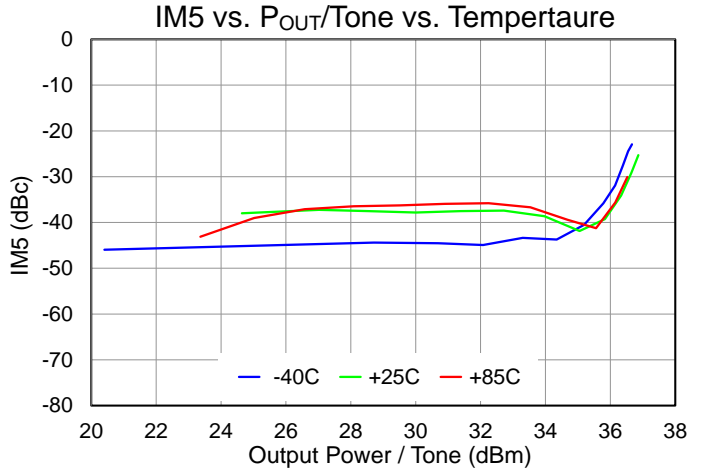
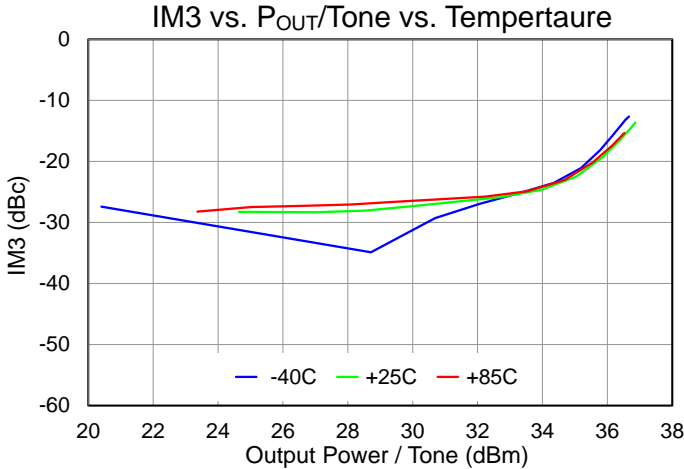
Performance Plots – Large Signal

Test conditions unless otherwise noted: Pulsed $V_D = 22\text{ V}$, $I_{DQ} = 290\text{ mA}$, Duty Cycle = 10%, $PW = 100\text{ us}$ CW input power, $T = +25\text{ }^\circ\text{C}$



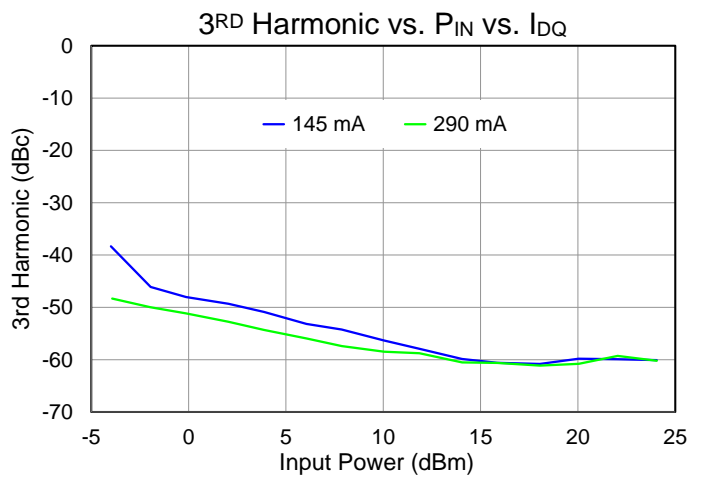
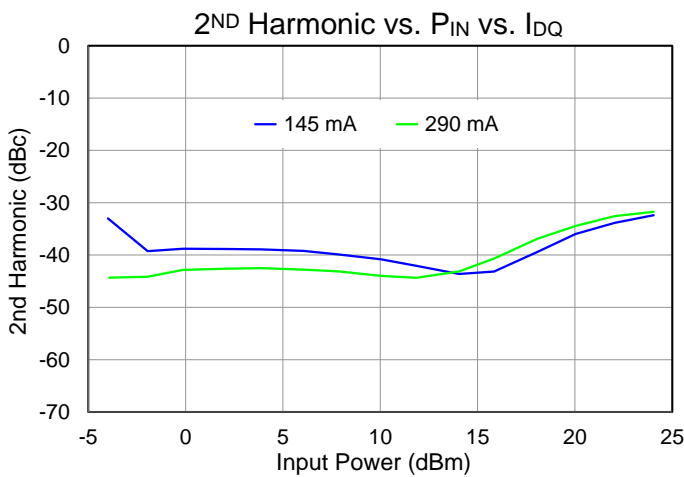
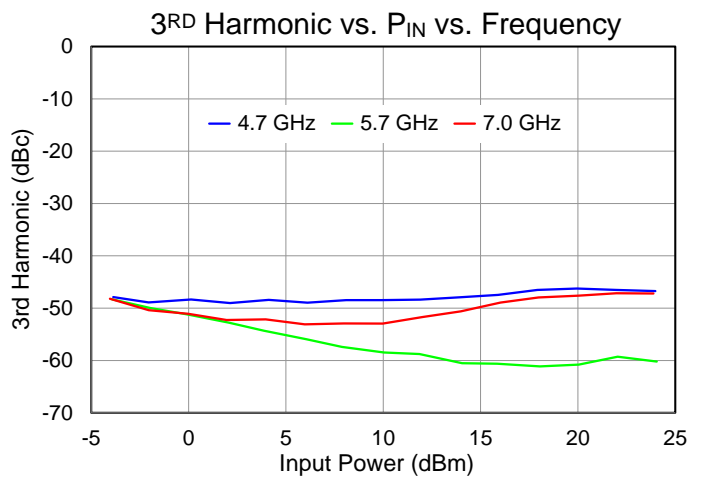
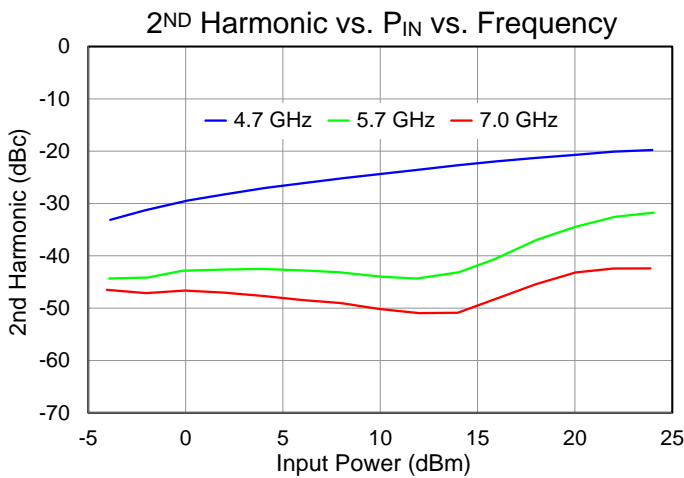
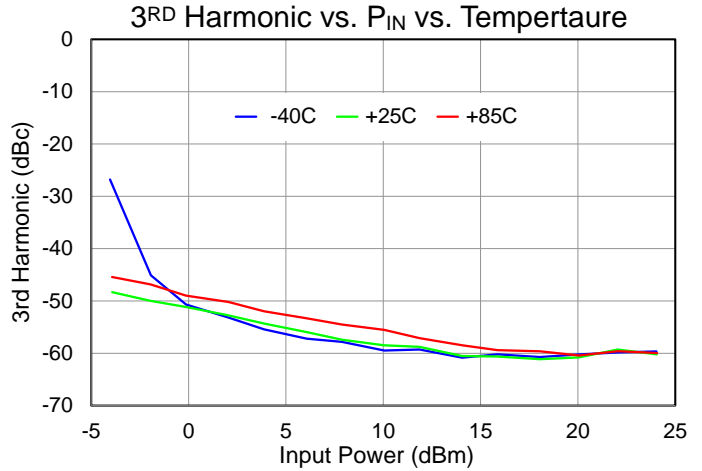
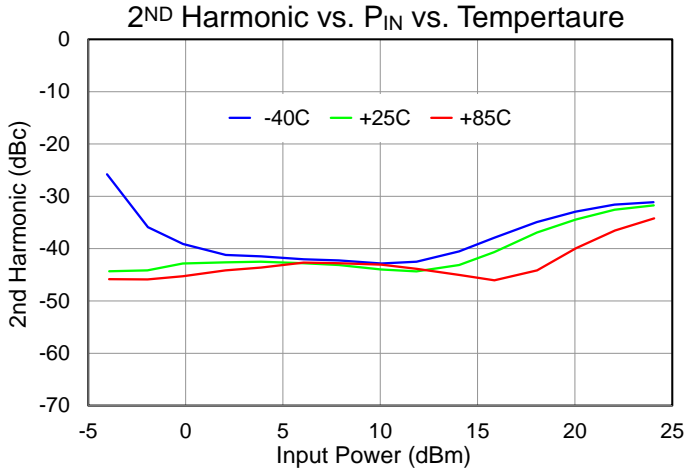
Performance Plots – Linearity

Test conditions unless otherwise noted: CW $V_D = 22\text{ V}$, $I_{DQ} = 290\text{ mA}$, CW input power, $T = +25^\circ\text{C}$, Freq. = 5.7 GHz, $\Delta F = 10\text{ MHz}$



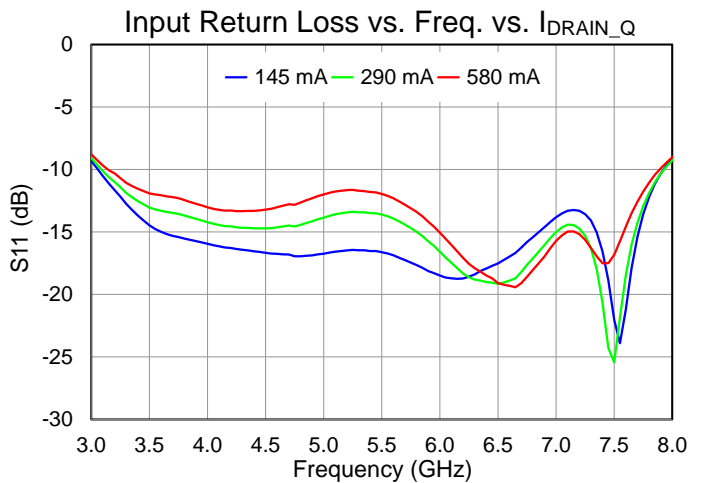
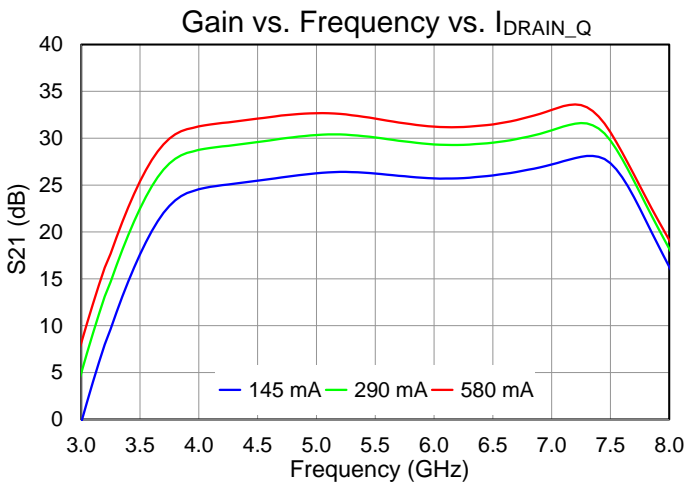
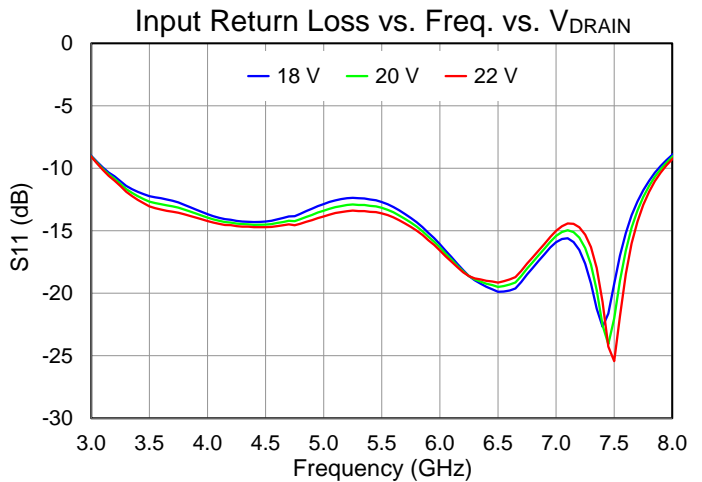
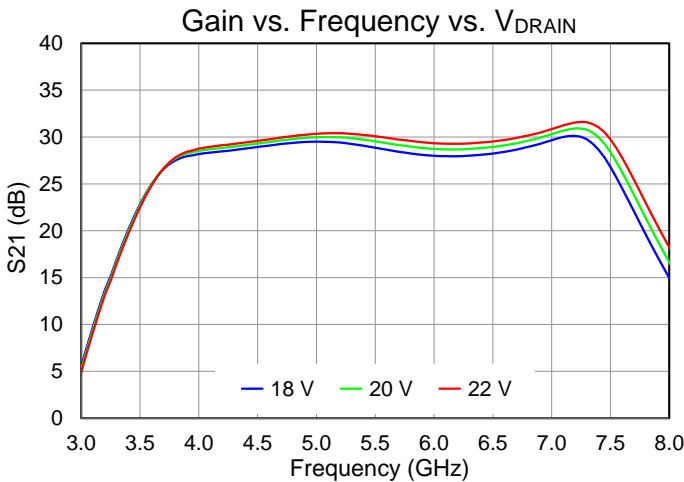
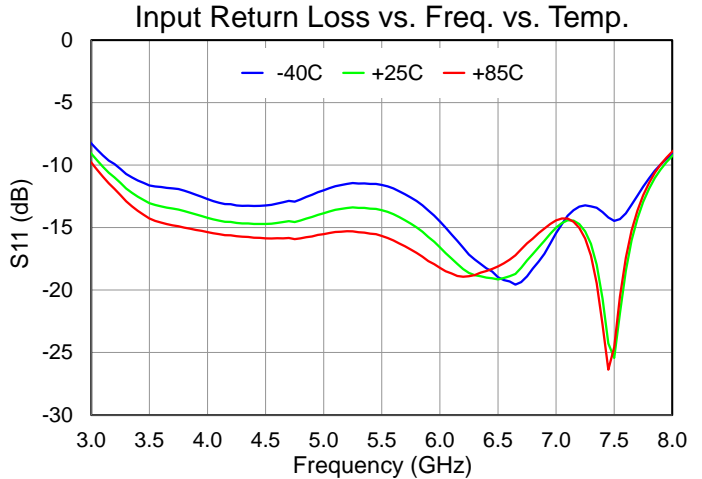
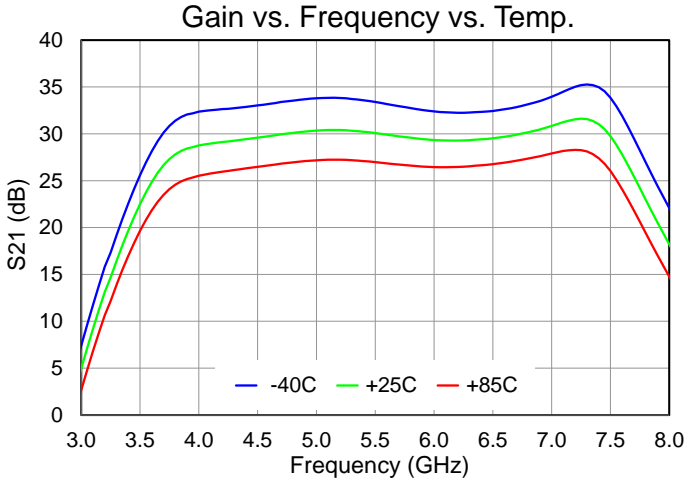
Performance Plots – Harmonics

Test conditions unless otherwise noted: CW $V_D = 20$ V, $I_{DQ} = 290$ mA, CW input power, $T = +25$ °C, Freq. = 5.7 GHz



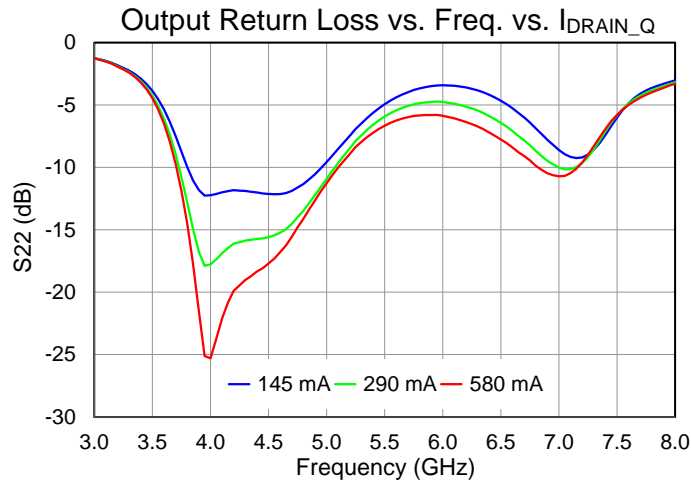
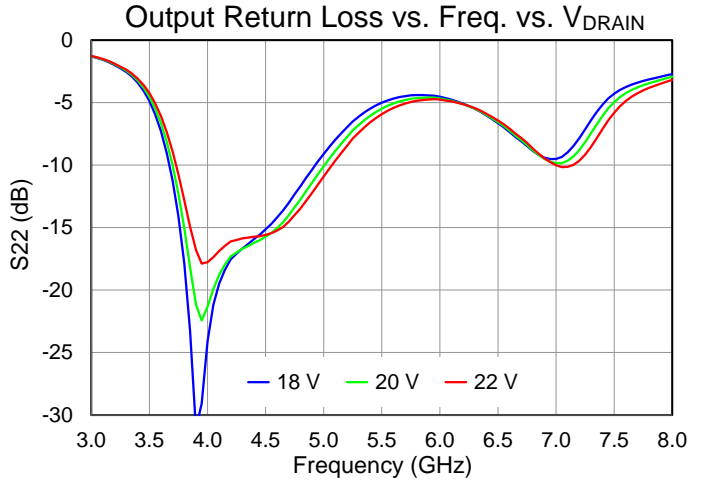
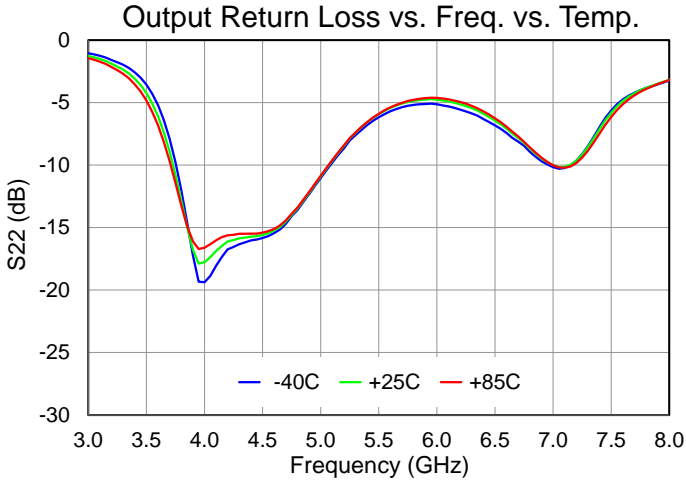
Performance Plots – Small Signal

Test conditions unless otherwise noted: CW $V_D = 22\text{ V}$, $I_{DQ} = 290\text{ mA}$, CW input power, $T = +25\text{ }^\circ\text{C}$



Performance Plots – Small Signal

Test conditions unless otherwise noted: CW $V_D = 22\text{ V}$, $I_{DQ} = 290\text{ mA}$, CW input power, $T = +25\text{ }^\circ\text{C}$

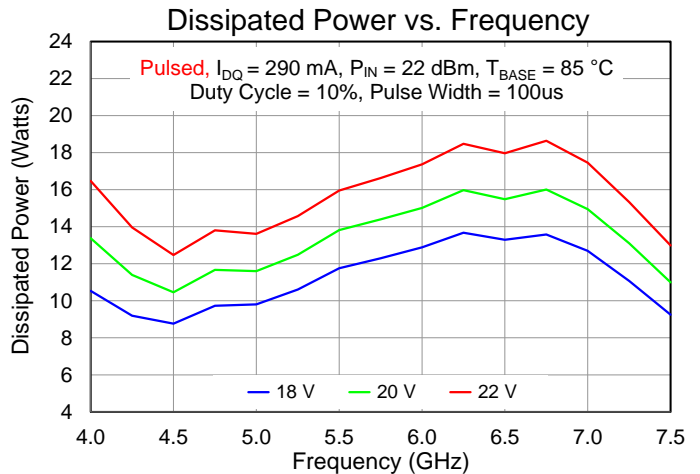
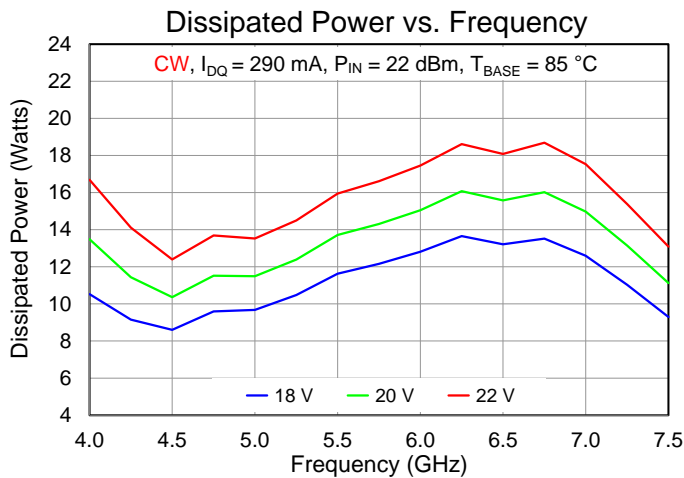


Thermal and Reliability Information

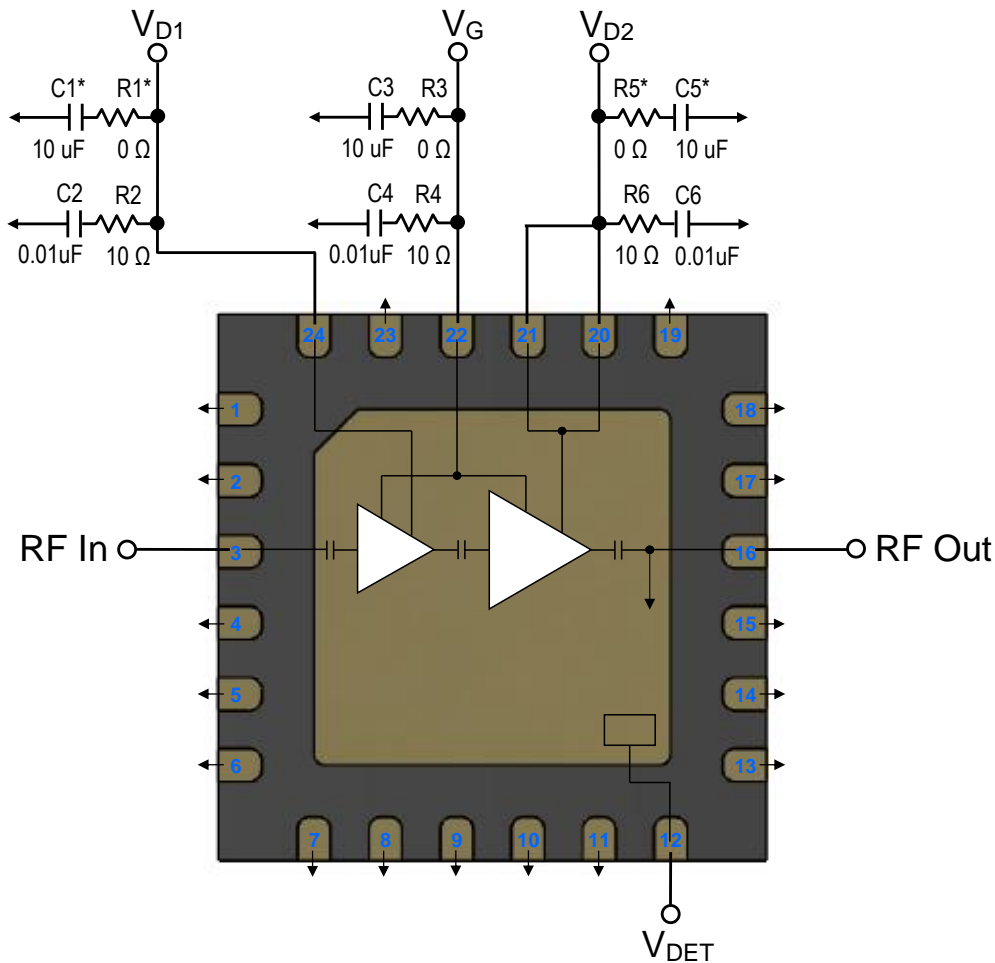
| Parameter | Test Conditions | Value | Units |
|--|--|---------|----------------------|
| Thermal Resistance (θ_{JC}) ⁽¹⁾ | $T_{base} = 85\text{ }^{\circ}\text{C}$ | 3.20 | $^{\circ}\text{C/W}$ |
| Channel Temperature, T_{CH} (Quiescent) ⁽²⁾ | $V_D = 22\text{ V}$, $I_{DQ} = 290\text{ mA}$ | 105 | $^{\circ}\text{C}$ |
| Median Lifetime (T_M) | $P_{DISS} = 6.38\text{ W}$ | 6.5E+11 | Hrs |
| Thermal Resistance (θ_{JC}) ⁽¹⁾ | $T_{base} = 85\text{ }^{\circ}\text{C}$, CW $V_D = 22\text{ V}$, $I_{DQ} = 290\text{ mA}$, Freq = 6.5 GHz, $I_{D_Drive} = 1.38\text{ A}$, $P_{IN} = 22\text{ dBm}$, $P_{OUT} = 41\text{ dBm}$, | 3.26 | $^{\circ}\text{C/W}$ |
| Channel Temperature, T_{CH} (Under RF) ⁽²⁾ | $P_{DISS} = 17.9\text{ W}$ | 143 | $^{\circ}\text{C}$ |
| Median Lifetime (T_M) | | 7.6E+08 | Hrs |
| Thermal Resistance (θ_{JC}) ⁽¹⁾ | $T_{base} = 85\text{ }^{\circ}\text{C}$, Pulsed $V_D = 22\text{ V}$, $I_{DQ} = 290\text{ mA}$, Freq = 6.5 GHz, $I_{D_Drive} = 1.38\text{ A}$, $P_{IN} = 22\text{ dBm}$, $P_{OUT} = 41\text{ dBm}$, | 2.13 | $^{\circ}\text{C/W}$ |
| Channel Temperature, T_{CH} (Under RF) ⁽²⁾ | $P_{DISS} = 17.9\text{ W}$ | 123 | $^{\circ}\text{C}$ |
| Median Lifetime (T_M) | | 2.3E+10 | Hrs |

Notes:

- Thermal resistance determined to the back of package (85 °C)
- Channel temperature indicated is an IR scan equivalent temperature. Thermal resistance is calculated using this value. Additional information can be found in the Qorvo Applications Note “GaN Device TCHMAX Theta-JC and Reliability Estimates,” located here <https://www.qorvo.com/products/d/da006480>



Applications Circuit



* Remove C1, C5, R1, R5 for pulsed drain operation

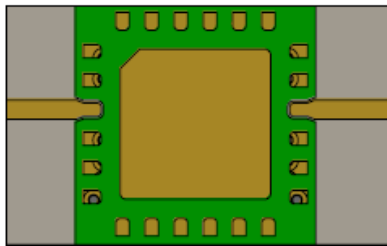
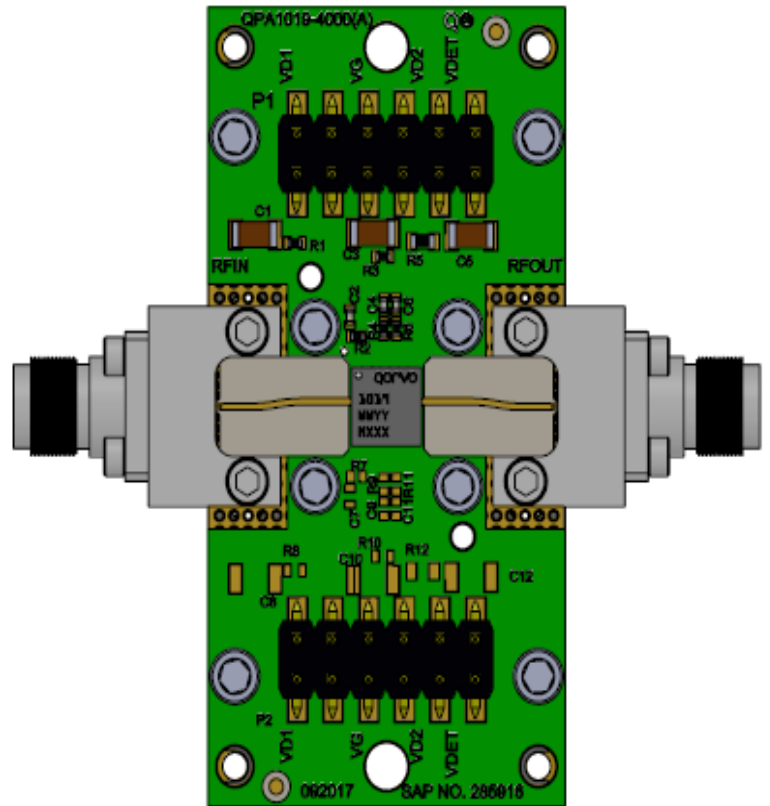
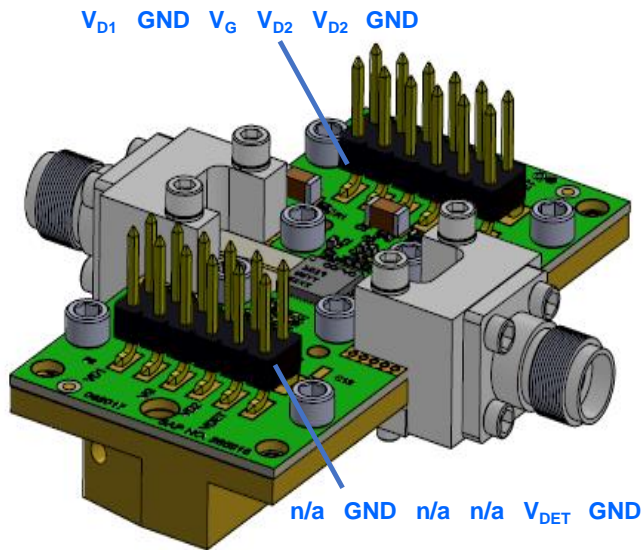
Bias-Up Procedure

1. Set I_D limit (CW) to 2000 mA, I_G limit to 20 mA
2. Set V_G to -5.0 V
4. Set V_D +22 V
5. Adjust V_G more positive until $I_{DQ} \approx 290$ mA ($V_G \sim -2.5$ V +/- Typical)
6. Apply RF signal

Bias-Down Procedure

1. Turn off RF signal
2. Reduce V_G to -5.0 V. Ensure $I_{DQ} \sim 0$ mA
4. Set V_D to 0 V
5. Turn off V_D supply
6. Turn off V_G supply

Application Evaluation Board (CW)



PCB Mounting

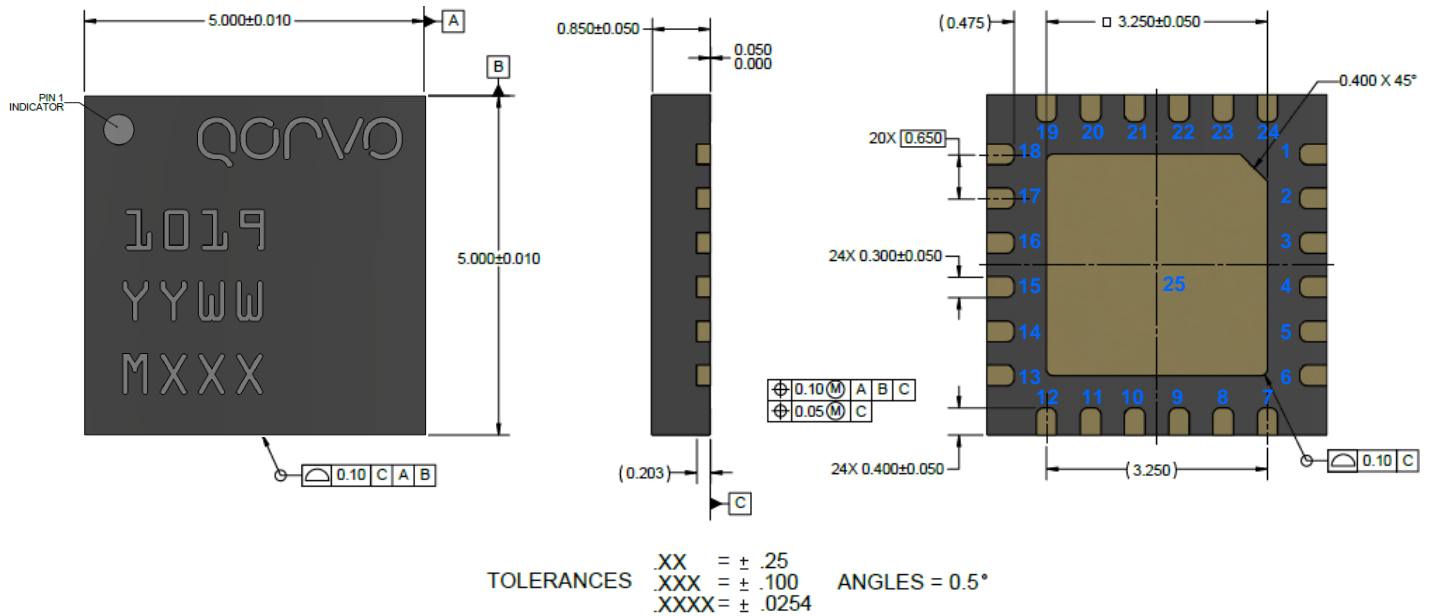
Notes:

1. RF PCB is Rogers 4003C; dielectric is 8 mil thick, copper cladding is ½ oz. copper both sides, plated to 1 oz
2. Copper Slug placed under the DUT to improve thermal and electrical performance

Bill of Materials

| Reference Des. | Value | Description | Manuf. | Part Number |
|----------------|---------|--|---------------------|-------------|
| C1, C3, C5 | 10 uF | CAP, 10uF, 20%, 50V, 20%, X5R, 1206 | Various | |
| C2, C4, C6 | 0.01 uF | CAP, 0.01uF, ±10%, 50V, X7R, 0402 | Various | |
| R1, R3 | 0 Ω | RES, 0 OHM, JMPR, 0402 | Various | |
| R2, R4, R6 | 10 Ω | RES, 10 OHM, 5%, 0.1W, 0402 | Various | |
| R5 | 0 Ω | RES, 0 OHM, JMPR, 0603 | Various | |
| H1, H2 | - | Header, connector 2x6, SMD | | |
| J1, J2 | - | Connector, Female, End Launch, 1092-01A-5 | Southwest Microwave | 1092-01A-5 |
| S1 – S7 | | Screw, Cap, socket head, 2-56x1/8" | | |
| PCB | - | Rogers 4003C, 8 mil dielectric, 1 oz. copper (gold plated), 2 layers | Rogers Corp. | Custom |
| Carrier | - | T-Carrier, Copper C110, 1.744 x 2.201 x 0.275" | | Custom |
| Solder | - | Paste, solder, syntech, Sn62/Pb36/Ag2 | | |
| Epoxy | - | Preform Epoxy, 0.986 x 1.996 x 0.003T | | |

Mechanical Information



Notes: unless otherwise specified;

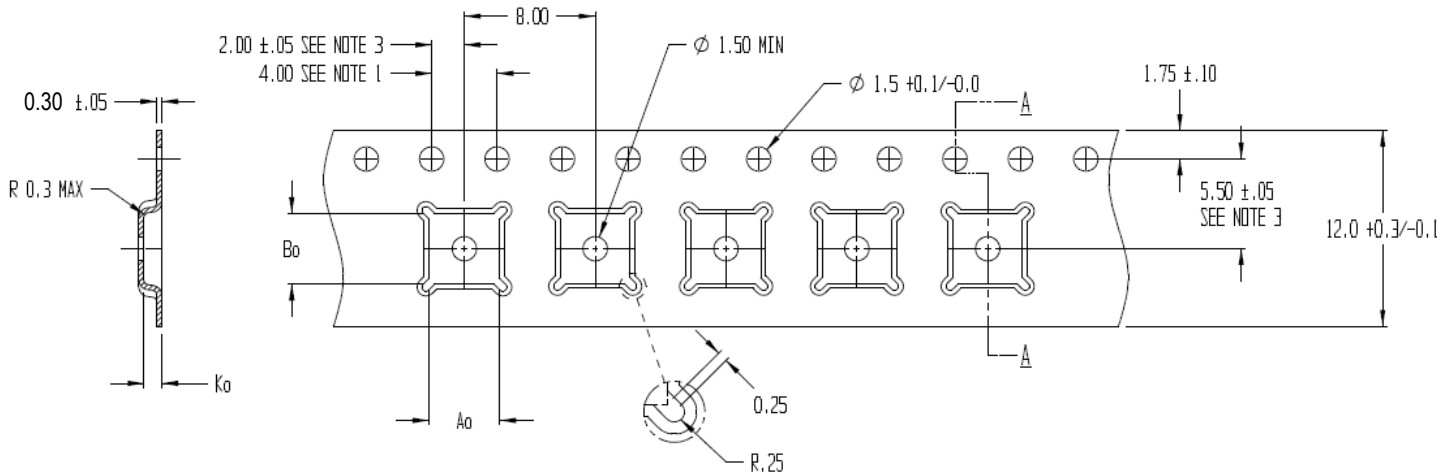
1. Dimensions: millimeters (mm)
2. Package leads are gold (Au) plated
3. Marking: YY is calendar year; WW is assembly week; MXXX is batch ID

Pin Description

| Pin Number | Symbol | Description |
|-----------------------------|------------------|--|
| 1-2, 4-11, 13-15, 17-19, 23 | NC | No internal connection. Recommend grounding at the PCB level. |
| 3 | RF Input | RF Input; matched to 50 Ω, DC blocked |
| 12 | V _{DET} | Output Power Detector Voltage |
| 16 | RF Output | RF Output; matched to 50 Ω, DC blocked, DC grounded |
| 20, 21 | V _{D2} | Drain voltage for stage 2. Bias network is required; see Application Circuit on page 14 as an example. |
| 22 | V _G | Gate voltage. Bias network is required; see Application Circuit on page 14 as an example. |
| 24 | V _{D1} | Drain voltage for stage 1. Bias network is required; see Application Circuit on page 14 as an example. |
| 25 | GND | Ground connection (center pad) |

Tape and reel Information

Standard T/R size = 250 pieces on a 7" reel
 Dimensions: millimeters (mm)
 Tolerances unless otherwise noted: .X = ± .2; .XX = ± .10



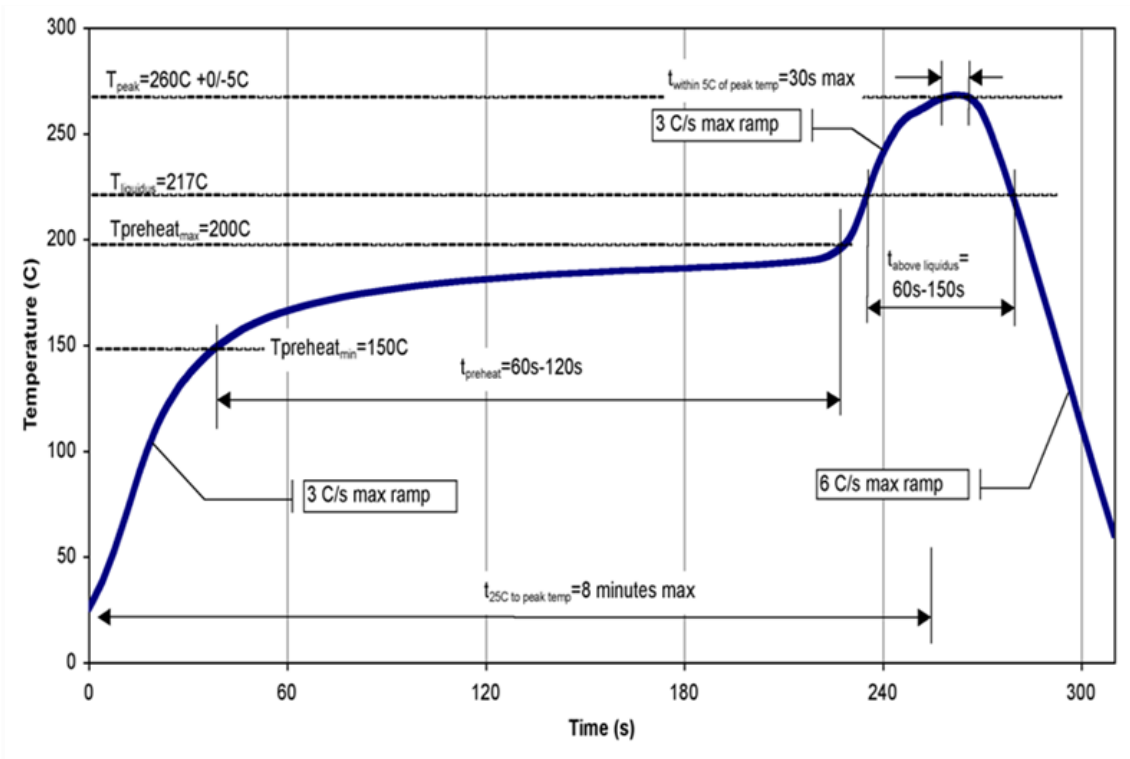
SECTION A - A

Ao = 5.25
 Bo = 5.25
 Ko = 1.10

Solderability

- Compatible with the latest version of J-STD-020, Lead-free solder, 260 °C
- Do not expose the package lid to temperatures > 280 °C

Recommended Soldering Temperature Profile



Handling Precautions

| Parameter | Rating | Standard |
|----------------------------------|--------|-----------------------|
| ESD – Human Body Model (HBM) | 1C | ANSI/ESD/JEDEC JS-001 |
| ESD – Charged Device Model (CDM) | C3 | ANSI/ESD/JEDEC JS-002 |
| MSL – Moisture Sensitivity Level | 3 | IPC/JEDEC J-STD-020 |



Caution!
 ESD-Sensitive Device

RoHS Compliance

This product is compliant with the 2011/65/EU RoHS directive (Restrictions on the Use of Certain Hazardous Substances in Electrical and Electronic Equipment), as amended by Directive 2015/863/EU.

This product also has the following attributes:

- Lead Free
- Halogen Free (Chlorine, Bromine)
- Antimony Free
- TBBP-A (C₁₅H₁₂Br₄O₂) Free
- PFOS Free
- SVHC Free

Contact Information

For the latest specifications, additional product information, worldwide sales and distribution locations:

Web: www.qorvo.com

Tel: 1-844-890-8163

Email: customer.support@qorvo.com

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